NSN 5961-01-212-8011

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View Online at https://aerobasegroup.com/nsn/5961-01-212-8011 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches **End Application:** Satellite communications set, an/wsc- (v) 9 **Internal Configuration:** Field effect-dual gate **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 25.0 drain to source voltage and 30.0 drain to gate voltage **Current Rating Per Characteristic:** 30.00 milliamperes source cutoff current of standard range **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Static discharge **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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